

Self-Assembly of Reduced Graphene Oxide at Liquid-Air Interface for Organic Field-Effect Transistors

By Shendong Ren, Rongjin Li, Xiangjian Meng and Hongxiang Li*

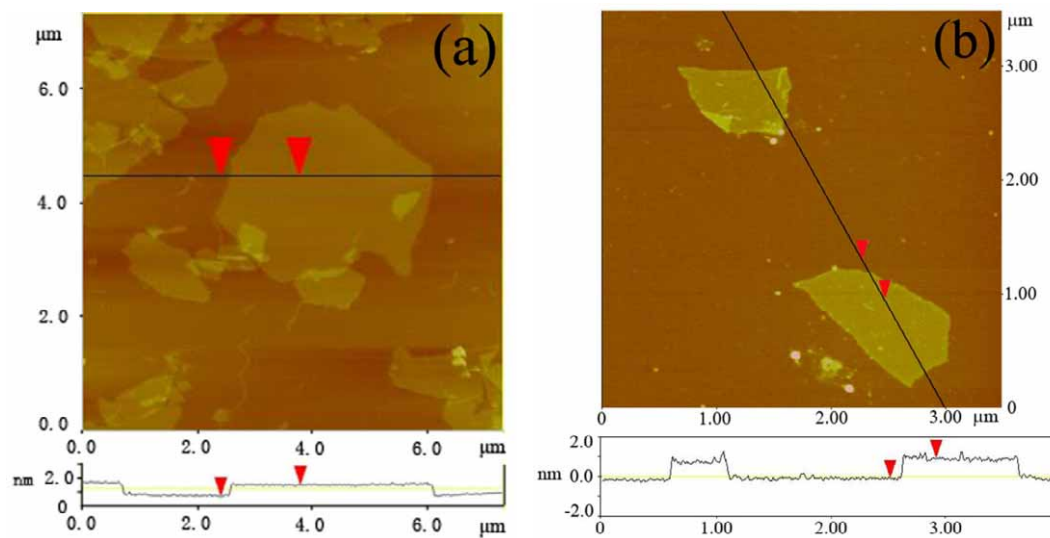


Fig. S1 AFM images of (a) GO and (b) RGO

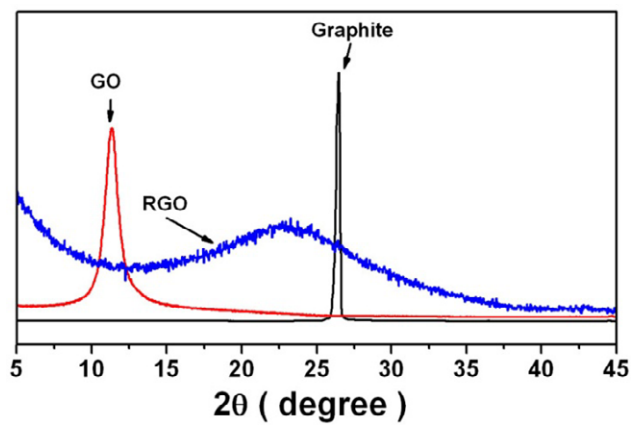


Fig. S2 XRD patterns of graphite, GO and RGO.

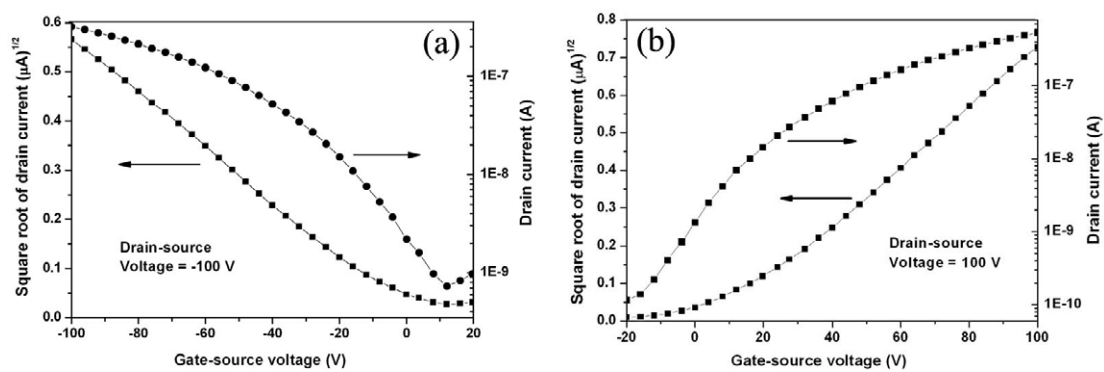


Fig. S3 Transfer characteristics of (a) CuPc based device and (b) F₁₆CuPc based device respectively with Au S/D electrode.

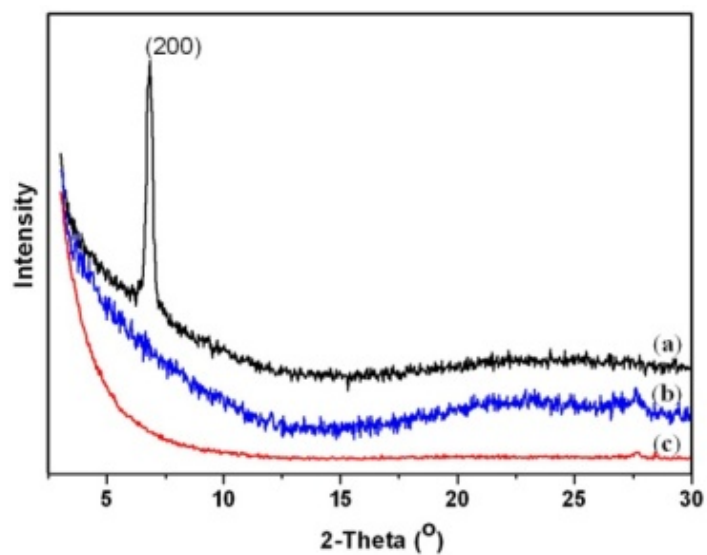


Fig. S4 XRD scattering patterns of the CuPc thin film on (a) SiO₂ dielectric, (b) RGO film, (c) gold film.